12A 28V$_{IN}$ DC/DC µModule Regulator with PLL, Output Tracking and Margining

FEATURES

- **Complete Switch Mode Power Supply**
- **Wide Input Voltage Range: 4.5V to 28V**
- **12A DC Typical, 14A Peak Output Current**
- **0.6V to 5V Output Voltage**
- **Output Voltage Tracking and Margining**
- **Parallel Multiple µModule® Regulators for Current Sharing**
- **Differential Remote Sensing for Precision Regulation**
- **PLL Frequency Synchronization**
- **±1.5% Regulation**
- **Current Foldback Protection (Disabled at Start-Up)**
- RoHS Compliant with Pb-Free Finish, Gold Finish LGA (e4) or SAC 305 BGA (e1)
- Ultrafast Transient Response
- Current Mode Control
- Up to 95% Efficiency at 5V$_{IN}$, 3.3V$_{OUT}$
- Programmable Soft-Start
- Output Overvoltage Protection
- Small Footprint, Low Profile (15mm × 15mm × 2.82mm) Surface Mount LGA and (15mm × 15mm × 3.42mm) BGA Packages

APPLICATIONS

- Telecom and Networking Equipment
- Servers
- Industrial Equipment
- Point of Load Regulation

DESCRIPTION

The LTM®4601HV is a complete 12A step-down switch mode DC/DC power supply with onboard switching controller, MOSFETs, inductor and all support components. The µModule regulator is housed in small surface mount 15mm × 15mm × 2.82mm LGA and 15mm × 15mm × 3.42mm BGA packages. Operating over an input voltage range of 4.5V to 28V, the LTM4601HV supports an output voltage range of 0.6V to 5V as well as output voltage tracking and margining. The high efficiency design delivers 12A continuous current (14A peak). Only bulk input and output capacitors are needed to complete the design.

The low profile and light weight package easily mounts in unused space on the back side of PC boards for high density point of load regulation. The µModule regulator can be synchronized with an external clock for reducing undesirable frequency harmonics and allows PolyPhase® operation for high load currents.

A high switching frequency and adaptive on-time current mode architecture deliver a very fast transient response to line and load changes without sacrificing stability. An onboard differential remote sense amplifier can be used to accurately regulate an output voltage independent of load current.
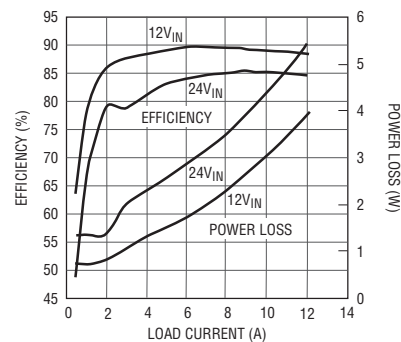
TYPICAL APPLICATION

2.5V/12A Power Supply with 4.5V to 28V Input
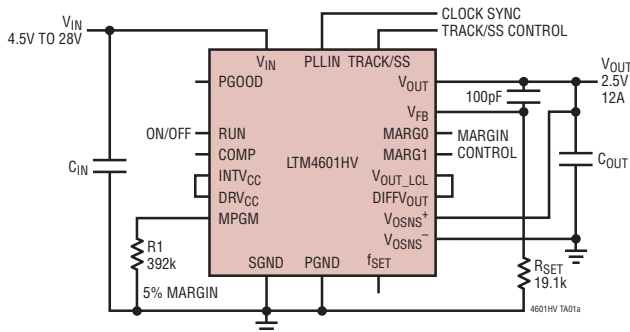
Efficiency and Power Loss vs Load Current

ABSOLUTE MAXIMUM RATINGS

(Note 1)

INTV$_{CC}$, DRV$_{CC}$, V$_{OUT\_LCL}$, V$_{OUT}$ (V$_{OUT}$ ≤ 3.3V with
Remote Sense Amp) .... −0.3V to 6V
PLLIN, TRACK/SS, MPGM, MARG0, MARG1,
PGOOD, f$_{SET}$ ....−0.3V to INTV$_{CC}$ + 0.3V
RUN .... −0.3V to 5V
V$_{FB}$, COMP .... −0.3V to 2.7V

V$_{IN}$ .... −0.3V to 28V
V$_{OSNS}$$^+$, V$_{OSNS}$$^-$ ....−0.3V to INTV$_{CC}$ + 0.3V
Operating Temperature Range (Note 2)....−40°C to 85°C
Junction Temperature .... 125°C
Storage Temperature Range .... −55°C to 125°C

PIN CONFIGURATION

TOP VIEW

LGA PACKAGE
118-LEAD (15mm × 15mm × 2.82mm)
T$_{JMAX}$ = 125°C, θ$_{JA}$ = 15°C/W, θ$_{JC}$ = 6°C/W,
θ$_{JA}$ DERIVED FROM 95mm × 76mm PCB WITH 4 LAYERS
WEIGHT = 1.7g

TOP VIEW

BGA PACKAGE
118-LEAD (15mm × 15mm × 3.42mm)
T$_{JMAX}$ = 125°C, θ$_{JA}$ = 15.5°C/W, θ$_{JC}$ = 6.5°C/W,
θ$_{JA}$ DERIVED FROM 95mm × 76mm PCB WITH 4 LAYERS
WEIGHT = 1.9g
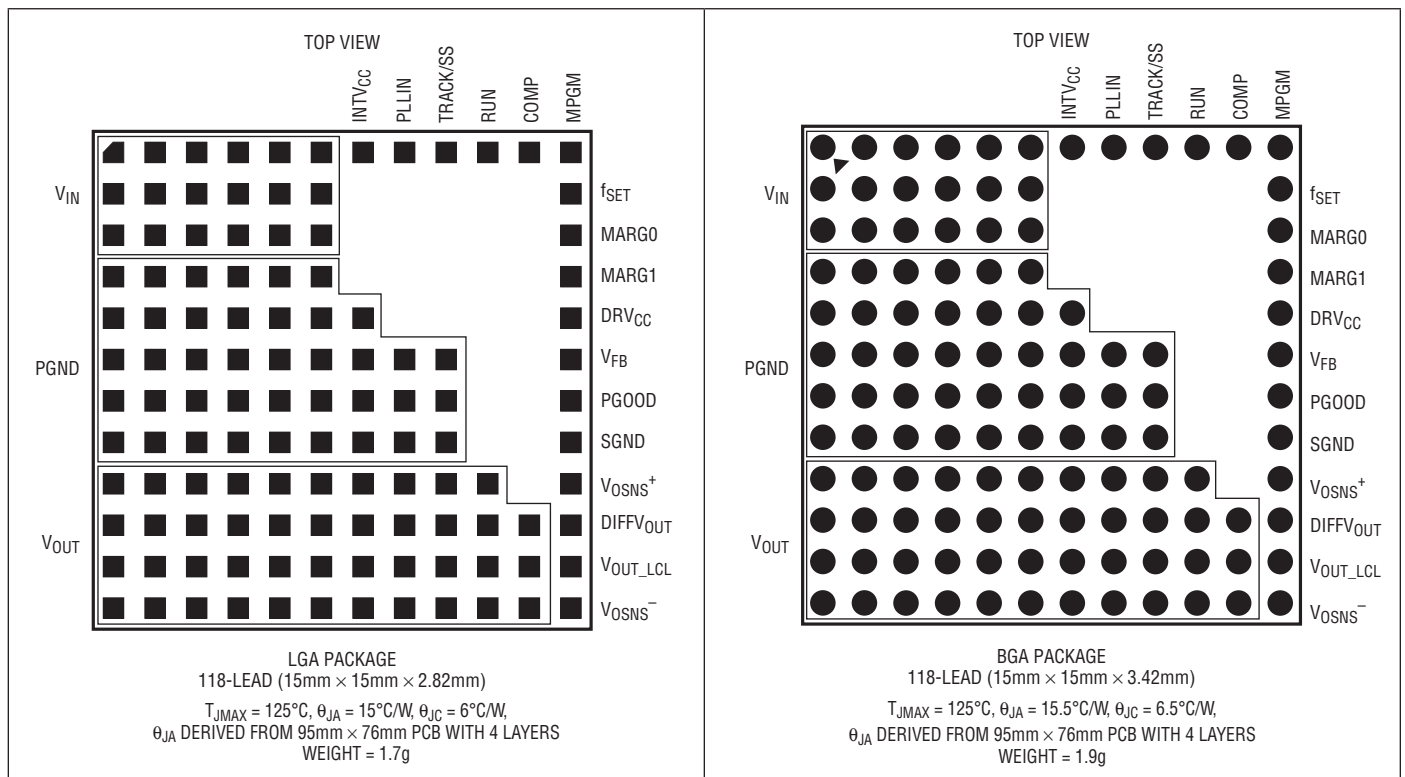
ORDER INFORMATION

LEAD FREE FINISH	TRAY	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTM4601HVEV#PBF	LTM4601HVEV#PBF	LTM4601HVV	118-Lead (15mm × 15mm × 2.82mm) LGA	−40°C to 85°C
LTM4601HVIV#PBF	LTM4601HVIV#PBF	LTM4601HVV	118-Lead (15mm × 15mm × 2.82mm) LGA	−40°C to 85°C
LTM4601HVEY#PBF	LTM4601HVEY#PBF	LTM4601HVY	118-Lead (15mm × 15mm × 3.42mm) BGA	−40°C to 85°C
LTM4601HVIY#PBF	LTM4601HVIY#PBF	LTM4601HVY	118-Lead (15mm × 15mm × 3.42mm) BGA	−40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/
This product is only offered in trays. For more information go to: http://www.linear.com/packaging/

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the –40°C to 85°C temperature range (Note 2), otherwise specifications are at T_A = 25°C, V_{IN} = 12V, per typical application (front page) configuration, R_{SET} = 40.2k.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
$V_{IN(DC)}$	Input DC Voltage		●	4.5		28	V
$V_{OUT(DC)}$	Output Voltage (With Remote Sense Amp)	C_{IN} = 10µF ×3, C_{OUT} = 200µF, R_{SET} = 40.2k V_{IN} = 12V, V_{OUT} = 1.5V, I_{OUT} = 0	●	1.478	1.5	1.522	V
Input Specifications							
$V_{IN(UVLO)}$	Undervoltage Lockout Threshold	I_{OUT} = 0A			3.2	4	V
$I_{INRUSH(VIN)}$	Input Inrush Current at Startup	I_{OUT} = 0A. V_{OUT} = 1.5V V_{IN} = 5V V_{IN} = 12V			0.6 0.7		A A
$I_{Q(VIN,NO LOAD)}$	Input Supply Bias Current	V_{IN} = 12V, No Switching V_{IN} = 12V, V_{OUT} = 1.5V, Switching Continuous V_{IN} = 5V, No Switching V_{IN} = 5V, V_{OUT} = 1.5V, Switching Continuous Shutdown, RUN = 0, VIN = 12V			3.8 38 2.5 42 22		mA mA mA mA µA
$I_{S(VIN)}$	Input Supply Current	V_{IN} = 12V, V_{OUT} = 1.5V, I_{OUT} = 12A V_{IN} = 12V, V_{OUT} = 3.3V, I_{OUT} = 12A V_{IN} = 5V, V_{OUT} = 1.5V, I_{OUT} = 12A			1.81 3.63 4.29		A A A
$INTV_{CC}$	V_{IN} = 12V, RUN > 2V	No Load		4.7	5	5.3	V
Output Specifications							
I_{OUTDC}	Output Continuous Current Range	V_{IN} = 12V, V_{OUT} = 1.5V (Note 5)		0		12	A
$\dfrac{\Delta V_{OUT(LINE)}}{V_{OUT}}$	Line Regulation Accuracy	V_{OUT} = 1.5V, I_{OUT} = 0A, V_{IN} from 4.5V to 28V	●			0.3	%
$\dfrac{\Delta V_{OUT(LOAD)}}{V_{OUT}}$	Load Regulation Accuracy	V_{OUT} = 1.5V, I_{OUT} = 0A to 12A, with RSA (Note 5) V_{IN} = 5V V_{IN} = 12V	● ●		0.25 0.25		% %
$V_{OUT(AC)}$	Output Ripple Voltage	I_{OUT} = 0A, C_{OUT} = 2× 100µF X5R Ceramic V_{IN} = 12V, V_{OUT} = 1.5V V_{IN} = 5V, V_{OUT} = 1.5V			20 18		mV_{P-P} mV_{P-P}
f_S	Output Ripple Voltage Frequency	I_{OUT} = 5A, V_{IN} = 12V, V_{OUT} = 1.5V			850		kHz
$\Delta V_{OUT(START)}$	Turn-On Overshoot	C_{OUT} = 200µF, V_{OUT} = 1.5V, I_{OUT} = 0A, TRACK/SS = 10nF V_{IN} = 12V V_{IN} = 5V			20 20		mV mV
t_{START}	Turn-On Time	C_{OUT} = 200µF, V_{OUT} = 1.5V, TRACK/SS = Open, I_{OUT} = 1A Resistive Load V_{IN} = 12V V_{IN} = 5V			0.5 0.5		ms ms
ΔV_{OUTLS}	Peak Deviation for Dynamic Load	Load: 0% to 50% to 0% of Full Load, C_{OUT} = 2 × 22µF Ceramic, 470µF 4V Sanyo POSCAP V_{IN} = 12V V_{IN} = 5V			35 35		mV mV
t_{SETTLE}	Settling Time for Dynamic Load Step	Load: 0% to 50%, or 50% to 0% of Full Load V_{IN} = 12V			25		µs
I_{OUTPK}	Output Current Limit	C_{OUT} = 200µF Ceramic V_{IN} = 12V, V_{OUT} = 1.5V V_{IN} = 5V, V_{OUT} = 1.5V			17 17		A A

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the –40°C to 85°C temperature range (Note 2), otherwise specifications are at T_A = 25°C, V_{IN} = 12V, per typical application (front page) configuration, R_{SET} = 40.2k.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Remote Sense Amp (Note 3)							
V_{OSNS}^+, V_{OSNS}^- CM Range	Common Mode Input Voltage Range	V_{IN} = 12V, RUN > 2V		0		$INTV_{CC}$ – 1	V
$DIFFV_{OUT}$ Range	Output Voltage Range	V_{IN} = 12V, $DIFFV_{OUT}$ Load = 100k		0		$INTV_{CC}$ – 1	V
V_{OS}	Input Offset Voltage Magnitude					1.25	mV
A_V	Differential Gain				1		V/V
GBP	Gain Bandwidth Product				3		MHz
SR	Slew Rate				2		V/µs
R_{IN}	Input Resistance	V_{OSNS}^+ to GND			20		kΩ
CMRR	Common Mode Rejection Mode				100		dB
Control Stage							
V_{FB}	Error Amplifier Input Voltage Accuracy	I_{OUT} = 0A, V_{OUT} = 1.5V	●	0.594	0.6	0.606	V
V_{RUN}	RUN Pin On/Off Threshold			1	1.5	1.9	V
$I_{TRACK/SS}$	Soft-Start Charging Current	$V_{TRACK/SS}$ = 0V		–1.0	–1.5	–2.0	µA
$t_{ON(MIN)}$	Minimum On Time	(Note 4)			50	100	ns
$t_{OFF(MIN)}$	Minimum Off Time	(Note 4)			250	400	ns
R_{PLLIN}	PLLIN Input Resistance				50		kΩ
I_{DRVCC}	Current into DRV_{CC} Pin	V_{OUT} = 1.5V, I_{OUT} = 1A, DRV_{CC} = 5V			18	25	mA
R_{FBHI}	Resistor Between V_{OUT_LCL} and V_{FB}			60.098	60.4	60.702	kΩ
V_{MPGM}	Margin Reference Voltage				1.18		V
V_{MARG0}, V_{MARG1}	MARG0, MARG1 Voltage Thresholds				1.4		V
PGOOD Output							
ΔV_{FBH}	PGOOD Upper Threshold	V_{FB} Rising		7	10	13	%
ΔV_{FBL}	PGOOD Lower Threshold	V_{FB} Falling		–7	–10	–13	%
$\Delta V_{FB(HYS)}$	PGOOD Hysteresis	V_{FB} Returning			1.5		%

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The LTM4601HV is tested under pulsed load conditions such that $T_J \approx T_A$. The LTM4601HVE is guaranteed to meet performance specifications from 0°C to 85°C. Specifications over the –40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls. The LTM4601HVI is guaranteed over the –40°C to 85°C temperature range.
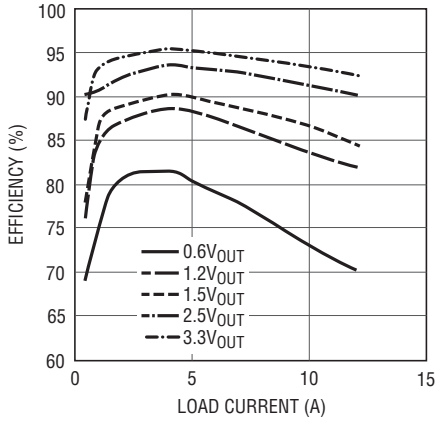
Note 3: Remote sense amplifier recommended for ≤3.3V output.

Note 4: 100% tested at wafer level only.

Note 5: See output current derating curves for different V_{IN}, V_{OUT} and T_A.
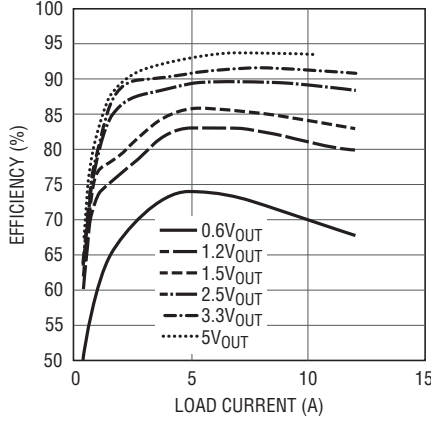
TYPICAL PERFORMANCE CHARACTERISTICS (See Figures 19 and 20 for all curves)

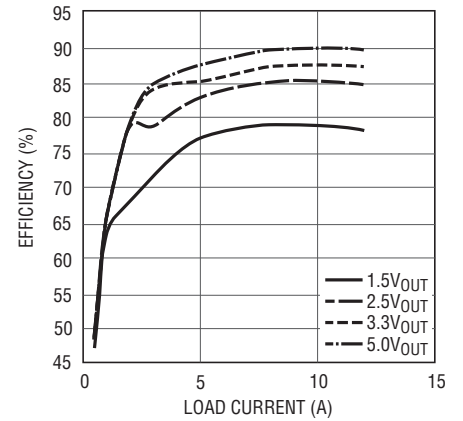**Efficiency vs Load Current with 5V_IN**

4601HV G01

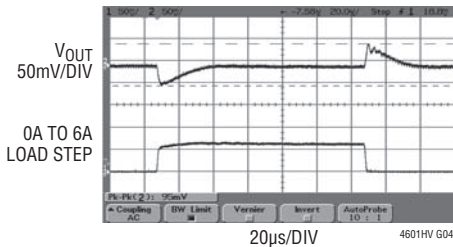**Efficiency vs Load Current with 12V_IN**

4601HV G02

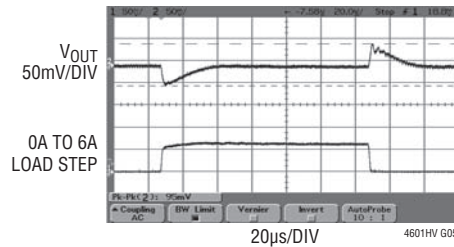**Efficiency vs Load Current with 24V_IN**

4601HV G03

1.2V Transient Response

20µs/DIV

4601HV G04

1.2V AT 6A/µs LOAD STEP
C_{OUT} = 3 • 22µF 6.3V CERAMICS
470µF 4V SANYO POSCAP
C3 = 100pF

1.5V Transient Response

20µs/DIV

4601HV G05

1.5V AT 6A/µs LOAD STEP
C_{OUT} = 3 • 22µF 6.3V CERAMICS
470µF 4V SANYO POSCAP
C3 = 100pF

1.8V Transient Response
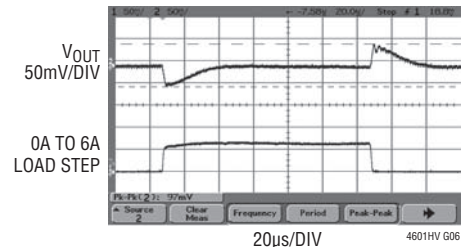
20µs/DIV

4601HV G06

1.8V AT 6A/µs LOAD STEP
C_{OUT} = 3 • 22µF 6.3V CERAMICS
470µF 4V SANYO POSCAP
C3 = 100pF

2.5V Transient Response

20µs/DIV
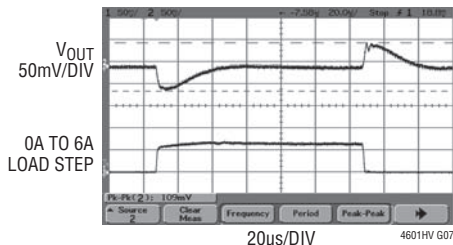
4601HV G07

2.5V AT 6A/µs LOAD STEP
C_{OUT} = 3 • 22µF 6.3V CERAMICS
470µF 4V SANYO POSCAP
C3 = 100pF

3.3V Transient Response

20µs/DIV

4601 G08
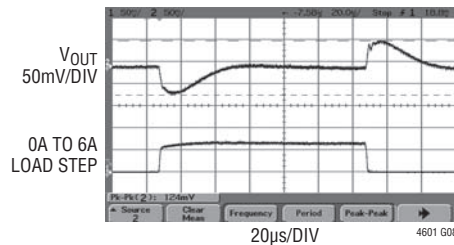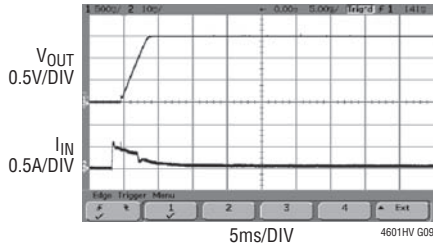
3.3V AT 6A/µs LOAD STEP
C_{OUT} = 3 • 22µF 6.3V CERAMICS
470µF 4V SANYO POSCAP
C3 = 100pF

TYPICAL PERFORMANCE CHARACTERISTICS (See Figures 19 and 20 for all curves)

Start-Up, I_{OUT} = 0A

V_OUT 0.5V/DIV

I_IN 0.5A/DIV

5ms/DIV   4601HV G09

V_{IN} = 12V
V_{OUT} = 1.5V
C_{OUT} = 470µF, 3 × 22µF
SOFT-START = 10nF

Start-Up, I_{OUT} = 12A (Resistive Load)

V_OUT 0.5V/DIV

I_IN 1A/DIV

2ms/DIV   4601HV G10
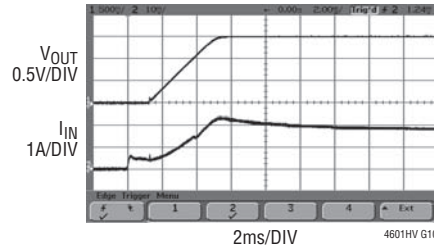
V_{IN} = 12V
V_{OUT} = 1.5V
C_{OUT} = 470µF, 3 × 22µF
SOFT-START = 10nF

V_{IN} to V_{OUT} Step-Down Ratio

— 3.3V OUTPUT WITH 130k FROM V_{OUT} TO I_{ON}

– – 5V OUTPUT WITH 100k RESISTOR ADDED FROM f_{SET} TO GND

- - - 5V OUTPUT WITH NO RESISTOR ADDED FROM f_{SET} TO GND

–·– 2.5V OUTPUT

–··– 1.8V OUTPUT

–···– 1.5V OUTPUT

······ 1.2V OUTPUT

OUTPUT VOLTAGE (V) vs INPUT VOLTAGE (V)
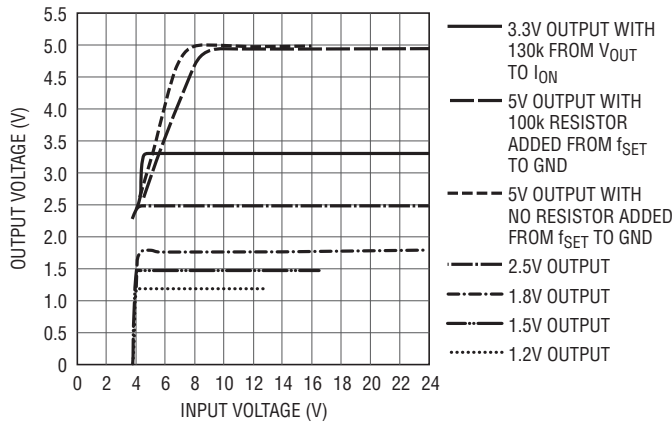
4601HV G11

Track, I_{OUT} = 12A
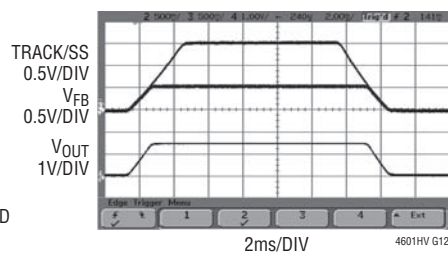
TRACK/SS 0.5V/DIV

V_FB 0.5V/DIV

V_OUT 1V/DIV

2ms/DIV   4601HV G12

V_{IN} = 12V
V_{OUT} = 1.5V
C_{OUT} = 470µF, 3 × 22µF
SOFT-START = 10nF

Short-Circuit Protection, I_{OUT} = 0A

V_OUT 0.5V/DIV

I_IN 1A/DIV

50µs/DIV   4601HV G13

V_{IN} = 12V
V_{OUT} = 1.5V
C_{OUT} = 470µF, 3 × 22µF
SOFT-START = 10nF

Short-Circuit Protection, I_{OUT} = 12A

V_OUT 0.5V/DIV

I_IN 1A/DIV

50µs/DIV   4601HV G14

V_{IN} = 12V
V_{OUT} = 1.5V
C_{OUT} = 470µF, 3 × 22µF
SOFT-START = 10nF

4601hvfb
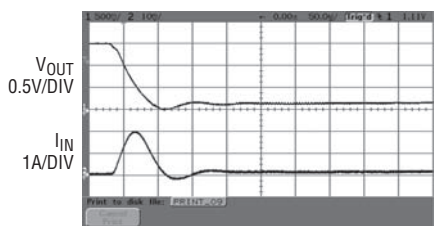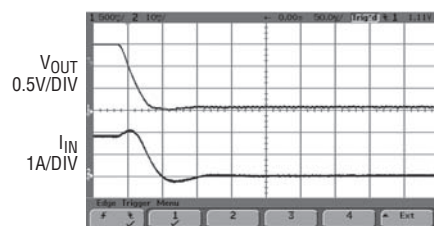
PIN FUNCTIONS (See Package Description for Pin Assignment)

V_{IN} **(Bank 1):** Power Input Pins. Apply input voltage between these pins and PGND pins. Recommend placing input decoupling capacitance directly between V_{IN} pins and PGND pins.

V_{OUT} **(Bank 3):** Power Output Pins. Apply output load between these pins and PGND pins. Recommend placing output decoupling capacitance directly between these pins and PGND pins. See Figure 17.

PGND (Bank 2): Power ground pins for both input and output returns.

V_{OSNS}^- **(Pin M12):** (–) Input to the Remote Sense Amplifier. This pin connects to the ground remote sense point. The remote sense amplifier is used for $V_{OUT} \leq 3.3V$. Tie to $INTV_{CC}$ if not used.

V_{OSNS}^+ **(Pin J12):** (+) Input to the Remote Sense Amplifier. This pin connects to the output remote sense point. The remote sense amplifier is used for $V_{OUT} \leq 3.3V$. Tie to ground if not used.

DIFFV$_{OUT}$ (Pin K12): Output of the Remote Sense Amplifier. This pin connects to the V_{OUT_LCL} pin. Leave floating if remote sense amplifier is not used.

DRV$_{CC}$ (Pin E12): This pin normally connects to $INTV_{CC}$ for powering the internal MOSFET drivers. This pin can be biased up to 6V from an external supply with about 50mA capability, or an external circuit as shown in Figure 18. This improves efficiency at the higher input voltages by reducing power dissipation in the module.

INTV$_{CC}$ (Pin A7): This pin is for additional decoupling of the 5V internal regulator.

PLLIN (Pin A8): External Clock Synchronization Input to the Phase Detector. This pin is internally terminated to SGND with a 50k resistor. Apply a clock with a high level above 2V and below $INTV_{CC}$. See the Applications Information section.

TRACK/SS (Pin A9): Output Voltage Tracking and Soft-Start Pin. When the module is configured as a master output, then a soft-start capacitor is placed on this pin to ground to control the master ramp rate. A soft-start capacitor can be used for soft-start turn on of a stand alone regulator. Slave operation is performed by putting a resistor divider from the master output to ground, and connecting the center point of the divider to this pin. See the Applications Information section.

MPGM (Pin A12): Programmable Margining Input. A resistor from this pin to ground sets a current that is equal to 1.18V/R. This current multiplied by 10kΩ will equal a value in millivolts that is a percentage of the 0.6V reference voltage. See Applications Information. To parallel LTM4601HVs, each requires an individual MPGM resistor. Do not tie MPGM pins together.

f$_{SET}$ (Pin B12): Frequency Set Internally to 850kHz. An external resistor can be placed from this pin to ground to increase frequency. See the Applications Information section for frequency adjustment.

V$_{FB}$ (Pin F12): The Negative Input of the Error Amplifier. Internally, this pin is connected to V_{OUT_LCL} pin with a 60.4k precision resistor. Different output voltages can be programmed with an additional resistor between V_{FB} and SGND pins. See the Applications Information section.

MARG0 (Pin C12): This pin is the LSB logic input for the margining function. Together with the MARG1 pin it will determine if margin high, margin low or no margin state is applied. The pin has an internal pull-down resistor of 50k. See the Applications Information section.

MARG1 (Pin D12): This pin is the MSB logic input for the margining function. Together with the MARG0 pin it will determine if margin high, margin low or no margin state is applied. The pin has an internal pull-down resistor of 50k. See the Applications Information section.

PIN FUNCTIONS (See Package Description for Pin Assignment)

SGND (Pin H12): Signal Ground. This pin connects to PGND at output capacitor point. See Figure 17.

COMP (Pin A11): Current Control Threshold and Error Amplifier Compensation Point. The current comparator threshold increases with this control voltage. The voltage ranges from 0V to 2.4V with 0.7V corresponding to zero sense voltage (zero current).

PGOOD (Pin G12): Output Voltage Power Good Indicator. Open-drain logic output that is pulled to ground when the output voltage is not within ±10% of the regulation point, after a 25µs power bad mask timer expires.

RUN (Pin A10): Run Control Pin. A voltage above 1.9V will turn on the module, and when below 1V, will turn off the module. A programmable UVLO function can be accomplished by connecting to a resistor divider from V_{IN} to ground. See Figure 1. This pin has a 5.1V Zener to ground. Maximum pin voltage is 5V. Limit current into the RUN pin to less than 1mA.

V$_{OUT\_LCL}$ (Pin L12): V_{OUT} connects directly to this pin to bypass the remote sense amplifier, or DIFFV$_{OUT}$ connects to this pin when remote sense amplifier is used.

SIMPLIFIED BLOCK DIAGRAM
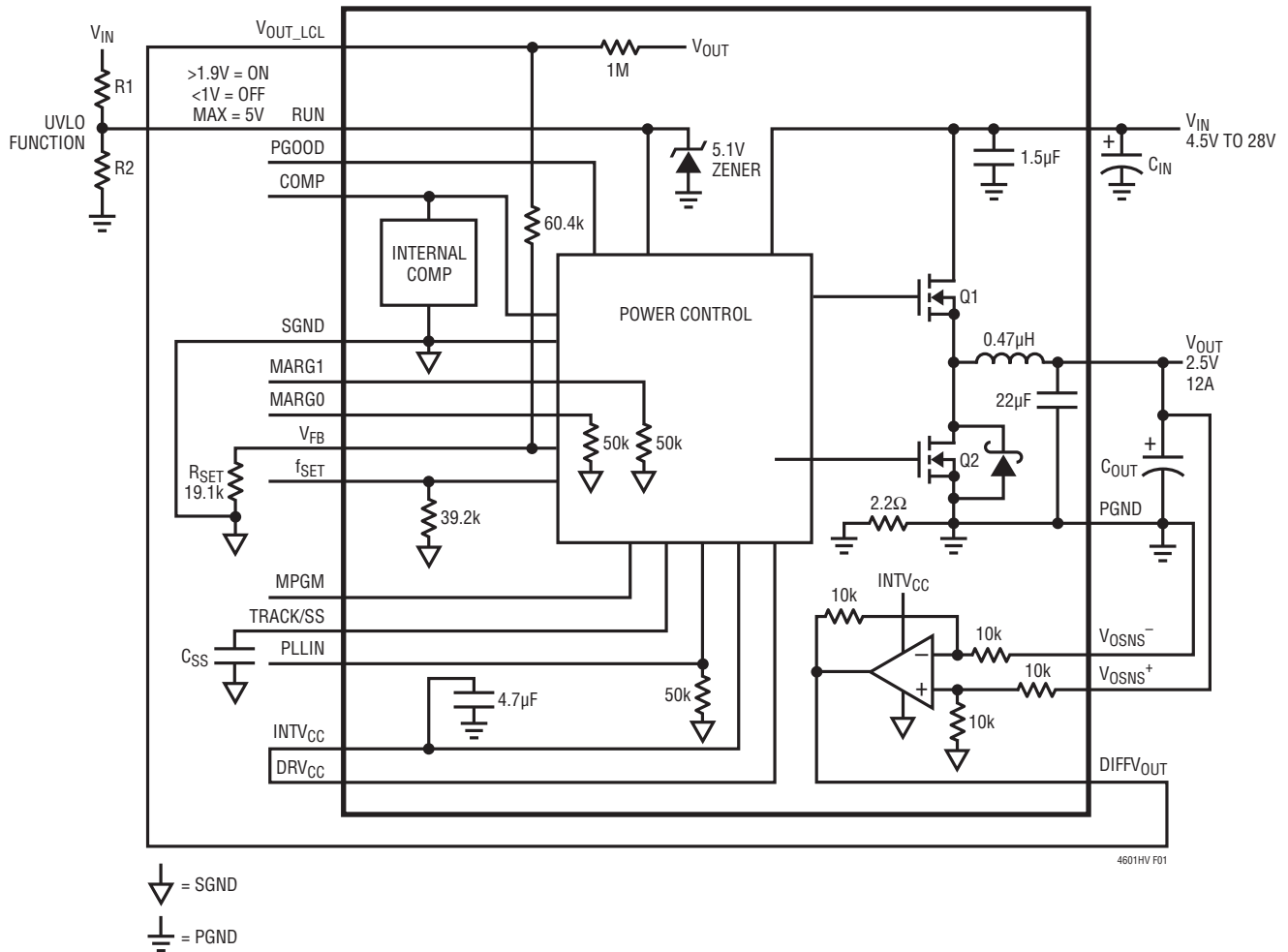
Figure 1. Simplified LTM4601HV Block Diagram

DECOUPLING REQUIREMENTS

T_A = 25°C, V_{IN} = 12V. Use Figure 1 configuration.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
C_{IN}	External Input Capacitor Requirement (V_{IN} = 4.5V to 28V, V_{OUT} = 2.5V)	I_{OUT} = 12A, 3× 10µF Ceramics	20	30		µF
C_{OUT}	External Output Capacitor Requirement (V_{IN} = 4.5V to 28V, V_{OUT} = 2.5V)	I_{OUT} = 12A	100	200		µF

OPERATION

Power Module Description

The LTM4601HV is a standalone nonisolated switching mode DC/DC power supply. It can deliver up to 12A of DC output current with some external input and output capacitors. This module provides a precisely regulated output voltage programmable via one external resistor from $0.6V_{DC}$ to $5.0V_{DC}$ over a 4.5V to 28V wide input voltage. The typical application schematics are shown in Figures 19 and 20.

The LTM4601HV has an integrated constant on-time current mode regulator, ultralow $R_{DS(ON)}$ FETs with fast switching speed and integrated Schottky diodes. The typical switching frequency is 850kHz at full load. With current mode control and internal feedback loop compensation, the LTM4601HV module has sufficient stability margins and good transient performance under a wide range of operating conditions and with a wide range of output capacitors, even all ceramic output capacitors.

Current mode control provides cycle-by-cycle fast current limit. Besides, foldback current limiting is provided in an overcurrent condition while V_{FB} drops. Internal overvoltage and undervoltage comparators pull the open-drain PGOOD output low if the output feedback voltage exits a ±10% window around the regulation point. Furthermore,

in an overvoltage condition, internal top FET Q1 is turned off and bottom FET Q2 is turned on and held on until the overvoltage condition clears.

Pulling the RUN pin below 1V forces the controller into its shutdown state, turning off both Q1 and Q2. At low load current, the module works in continuous current mode by default to achieve minimum output voltage ripple.

When DRV_{CC} pin is connected to $INTV_{CC}$ an integrated 5V linear regulator powers the internal gate drivers. If a 5V external bias supply is applied on the DRV_{CC} pin, then an efficiency improvement will occur due to the reduced power loss in the internal linear regulator. This is especially true at the high end of the input voltage range.

The LTM4601HV has a very accurate differential remote sense amplifier with very low offset. This provides for very accurate output voltage sensing at the load. The MPGM pin, MARG0 pin and MARG1 pin are used to support voltage margining, where the percentage of margin is programmed by the MPGM pin, and MARG0 and MARG1 select margining.

The PLLIN pin provides frequency synchronization of the device to an external clock. The TRACK/SS pin is used for power supply tracking and soft-start programming.

APPLICATIONS INFORMATION

The typical LTM4601HV application circuits are shown in Figures 19 and 20. External component selection is primarily determined by the maximum load current and output voltage. Refer to Table 2 for specific external capacitor requirements for a particular application.

V_{IN} to V_{OUT} Step-Down Ratios

There are restrictions in the maximum V_{IN} to V_{OUT} step down ratio that can be achieved for a given input voltage. These constraints are shown in the Typical Performance Characteristics curves labeled V_{IN} to V_{OUT} Step-Down Ratio. Note that additional thermal derating may apply. See the Thermal Considerations and Output Current Derating section of this data sheet.

Output Voltage Programming and Margining

The PWM controller has an internal 0.6V reference voltage. As shown in the Block Diagram, a 1M and a 60.4k 0.5% internal feedback resistor connects V_{OUT} and V_{FB} pins together. The V_{OUT_LCL} pin is connected between the 1M and the 60.4k resistor. The 1M resistor is used to protect against an output overvoltage condition if the V_{OUT_LCL} pin is not connected to the output, or if the remote sense amplifier output is not connected to V_{OUT_LCL}. In these cases, the output voltage will default to 0.6V. Adding a resistor R_{SET} from the V_{FB} pin to SGND pin programs the output voltage:

$$V_{OUT} = 0.6V \frac{60.4k + R_{SET}}{R_{SET}}$$

or equivalently:

$$R_{SET} = \frac{60.4k}{\left(\dfrac{V_{OUT}}{0.6V} - 1\right)}$$

Table 1. R_{SET} Standard 1% Resistor Values vs V_{OUT}

R_{SET} (kΩ)	Open	60.4	40.2	30.1	25.5	19.1	13.3	8.25
V_{OUT} (V)	0.6	1.2	1.5	1.8	2	2.5	3.3	5

The MPGM pin programs a current that when multiplied by an internal 10k resistor sets up the 0.6V reference ± offset for margining. A 1.18V reference divided by the RPGM resistor on the MPGM pin programs the current. Calculate $V_{OUT(MARGIN)}$:

$$V_{OUT(MARGIN)} = \frac{\%V_{OUT}}{100} \bullet V_{OUT}$$

where $\%V_{OUT}$ is the percentage of V_{OUT} you want to margin, and $V_{OUT(MARGIN)}$ is the margin quantity in volts:

$$R_{PGM} = \frac{V_{OUT}}{0.6V} \bullet \frac{1.18V}{V_{OUT(MARGIN)}} \bullet 10k$$

where R_{PGM} is the resistor value to place on the MPGM pin to ground.

The margining voltage, $V_{OUT(MARGIN)}$, will be added or subtracted from the nominal output voltage as determined by the state of the MARG0 and MARG1 pins. See the truth table below:

MARG1	MARG0	MODE
LOW	LOW	NO MARGIN
LOW	HIGH	MARGIN UP
HIGH	LOW	MARGIN DOWN
HIGH	HIGH	NO MARGIN

Input Capacitors

LTM4601HV module should be connected to a low AC impedance DC source. Input capacitors are required to be placed adjacent to the module. In Figure 20, the 10µF ceramic input capacitors are selected for their ability to handle the large RMS current into the converter. An input bulk capacitor of 100µF is optional. This 100µF capacitor is only needed if the input source impedance is compromised by long inductive leads or traces.

For a buck converter, the switching duty-cycle can be estimated as:

$$D = \frac{V_{OUT}}{V_{IN}}$$

APPLICATIONS INFORMATION

Without considering the inductor ripple current, the RMS current of the input capacitor can be estimated as:

$$I_{CIN(RMS)} = \frac{I_{OUT(MAX)}}{\eta\%} \bullet \sqrt{D \bullet (1-D)}$$

In the above equation, $\eta\%$ is the estimated efficiency of the power module. C_{IN} can be a switcher-rated electrolytic aluminum capacitor, OS-CON capacitor or high value ceramic capacitor. Note the capacitor ripple current ratings are often based on temperature and hours of life. This makes it advisable to properly derate the input capacitor, or choose a capacitor rated at a higher temperature than required. Always contact the capacitor manufacturer for derating requirements.

In Figures 19 and 20, the 10µF ceramic capacitors are together used as a high frequency input decoupling capacitor. In a typical 12A output application, three very low ESR, X5R or X7R, 10µF ceramic capacitors are recommended. These decoupling capacitors should be placed directly adjacent to the module input pins in the PCB layout to minimize the trace inductance and high frequency AC noise. Each 10µF ceramic is typically good for 2A to 3A of RMS ripple current. Refer to your ceramics capacitor catalog for the RMS current ratings.

Multiphase operation with multiple LTM4601HV devices in parallel will lower the effective input RMS ripple current due to the interleaving operation of the regulators. Application Note 77 provides a detailed explanation. Refer to Figure 2 for the input capacitor ripple current reduction as a function of the number of phases. The figure provides a ratio of RMS ripple current to DC load current as function of duty cycle and the number of paralleled phases. Pick the corresponding duty cycle and the number of phases to arrive at the correct ripple current value. For example, the 2-phase parallel LTM4601HV design provides 24A at 2.5V output from a 12V input. The duty cycle is DC = 2.5V/12V = 0.21. The 2-phase curve has a ratio of ~0.25 for a duty cycle of 0.21. This 0.25 ratio of RMS ripple current to a DC load current of 24A equals ~6A of input RMS ripple current for the external input capacitors.

Output Capacitors

The LTM4601HV is designed for low output ripple voltage. The bulk output capacitors defined as C_{OUT} are chosen with low enough effective series resistance (ESR) to meet the output voltage ripple and transient requirements. C_{OUT} can be a low ESR tantalum capacitor, a low ESR polymer capacitor or a ceramic capacitor. The typical capacitance is 200µF if all ceramic output capacitors are used. Additional output filtering may be required by the system designer if further reduction of output ripple or dynamic transient spike is required. Table 2 shows a matrix of different output voltages and output capacitors to minimize the voltage droop and overshoot during a 5A/µs transient. The table optimizes total equivalent ESR and total bulk capacitance to maximize transient performance.
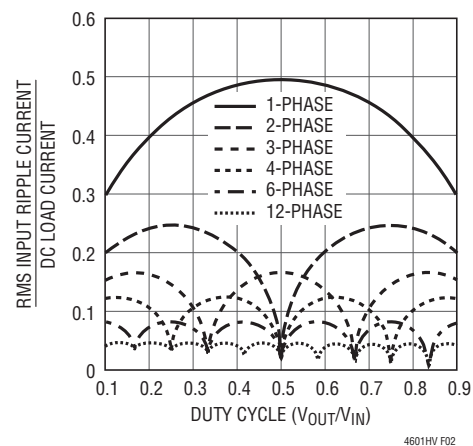
Figure 2. Normalized Input RMS Ripple Current vs Duty Cycle for One to Six Modules (Phases)

APPLICATIONS INFORMATION

Multiphase operation with multiple LTM4601HV devices in parallel will lower the effective output ripple current due to the interleaving operation of the regulators. For example, each LTM4601HV's inductor current in a 12V to 2.5V multiphase design can be read from the Inductor

Ripple Current vs Duty Cycle graph (Figure 3). The large ripple current at low duty cycle and high output voltage can be reduced by adding an external resistor from f_{SET} to ground which increases the frequency. If the duty cycle is DC = 2.5V/12V = 0.21, the inductor ripple current for 2.5V output at 21% duty cycle is ~6A in Figure 3.

Figure 4 provides a ratio of peak-to-peak output ripple current to the inductor current as a function of duty cycle and the number of paralleled phases. Pick the corresponding duty cycle and the number of phases to arrive at the correct output ripple current ratio value. If a 2-phase operation is chosen at a duty cycle of 21%, then 0.6 is the ratio. This 0.6 ratio of output ripple current to inductor ripple of 6A equals 3.6A of effective output ripple current. Refer to Application Note 77 for a detailed explanation of output ripple current reduction as a function of paralleled phases.

The output ripple voltage has two components that are related to the amount of bulk capacitance and effective series resistance (ESR) of the output bulk capacitance.

Figure 3. Inductor Ripple Current vs Duty Cycle
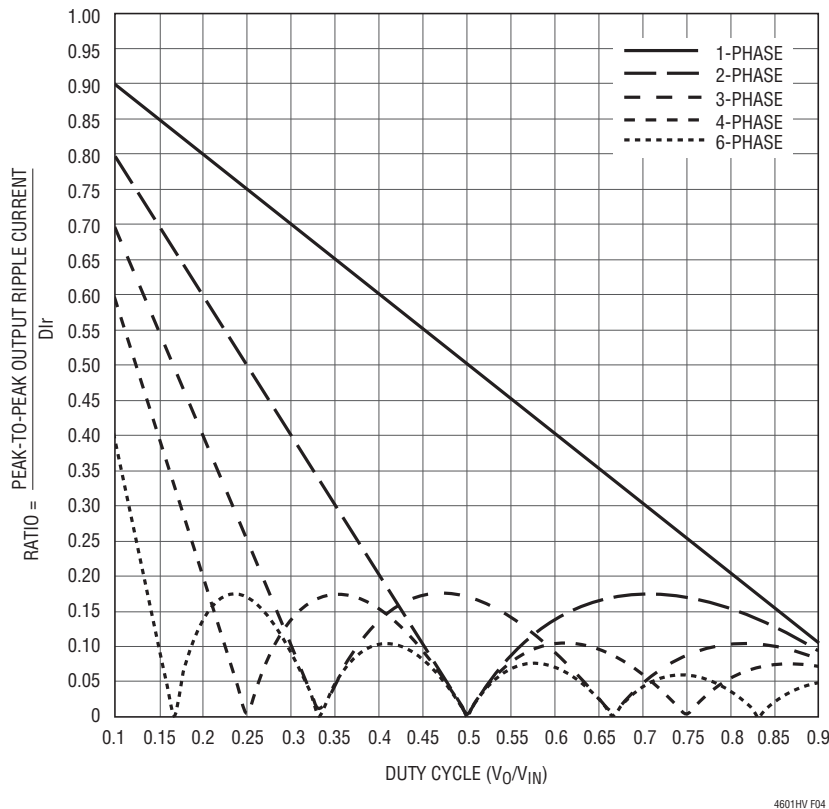
Figure 4. Normalized Output Ripple Current vs Duty Cycle, DIr = V_OT/L_I, DIr = Each Phase's Inductor Current

APPLICATIONS INFORMATION

Therefore, the output ripple voltage can be calculated with the known effective output ripple current. The equation: $\Delta V_{OUT(P-P)} \approx (\Delta I_L/(8 \bullet f \bullet m \bullet C_{OUT}) + ESR \bullet \Delta I_L)$, where f is frequency and m is the number of parallel phases. This calculation process can be easily accomplished by using LTpowerCAD™.

Fault Conditions: Current Limit and Overcurrent Foldback

LTM4601HV has a current mode controller, which inherently limits the cycle-by-cycle inductor current not only in steady-state operation, but also in response to transients.

To further limit current in the event of an overload condition, the LTM4601HV provides foldback current limiting. If the output voltage falls by more than 50%, then the maximum output current is progressively lowered to about one sixth of its full current limit value. The current limit returns to its nominal value once V_{OUT} and V_{FB} have returned to their nominal values.

Soft-Start and Tracking

The TRACK/SS pin provides a means to either soft-start the regulator or track it to a different power supply. A capacitor on this pin will program the ramp rate of the output voltage. A 1.5µA current source will charge up the external soft-start capacitor to 80% of the 0.6V internal voltage reference plus or minus any margin delta. This will control the ramp of the internal reference and the output voltage. The total soft-start time can be calculated as:

$$t_{SOFTSTART} = 0.8 \bullet \left(0.6V \pm V_{OUT(MARGIN)}\right) \bullet \frac{C_{SS}}{1.5\mu A}$$

When the RUN pin falls below 1.5V, then the TRACK/SS pin is reset to allow for proper soft-start control when the regulator is enabled again. Current foldback and forced continuous mode are disabled during the soft-start process. The soft-start function can also be used to control the output ramp up time, so that another regulator can be easily tracked to it.

Output Voltage Tracking

Output voltage tracking can be programmed externally using the TRACK/SS pin. The output can be tracked up and down with another regulator. The master regulator's output is divided down with an external resistor divider that is the same as the slave regulator's feedback divider. Figure 5 shows an example of coincident tracking. Ratiometric modes of tracking can be achieved by selecting different resistor values to change the output tracking ratio. The master output must be greater than the slave output for the tracking to work. Figure 6 shows the coincident output tracking characteristics.
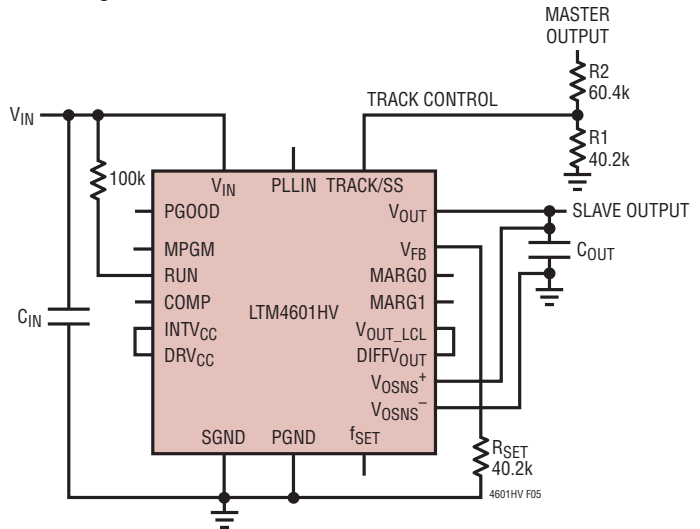

Figure 5. Coincident Tracking Schematic
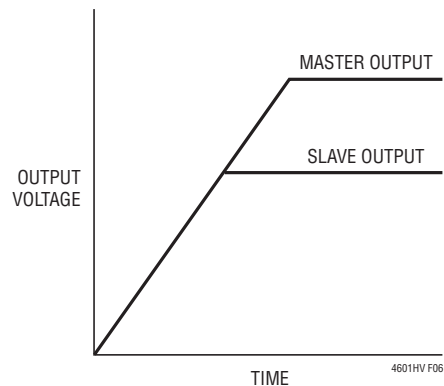
Figure 6. Coincident Output Tracking Characteristics

APPLICATIONS INFORMATION

Run Enable

The RUN pin is used to enable the power module. The pin has an internal 5.1V Zener to ground. The pin can be driven with a logic input not to exceed 5V.

The RUN pin can also be used as an undervoltage lock out (UVLO) function by connecting a resistor divider from the input supply to the RUN pin:

$$V_{UVLO} = \frac{R1+R2}{R2} \bullet 1.5V$$

See Figure 1, Simplified Block Diagram.

Power Good

The PGOOD pin is an open-drain pin that can be used to monitor valid output voltage regulation. This pin monitors a ±10% window around the regulation point and tracks with margining.

COMP Pin

This pin is the external compensation pin. The module has already been internally compensated for most output voltages. Table 2 is provided for most application requirements. LTpowerCAD is available for other control loop optimization.

PLLIN

The power module has a phase-locked loop comprised of an internal voltage controlled oscillator and a phase detector. This allows the internal top MOSFET turn-on to be locked to the rising edge of the external clock. The frequency range is ±30% around the operating frequency of 850kHz. A pulse detection circuit is used to detect a clock on the PLLIN pin to turn on the phase-locked loop. The pulse width of the clock has to be at least 400ns and at least 2V in amplitude. The PLLIN pin must be driven from a low impedance source such as a logic gate located close to the pin. During the start-up of the regulator, the phase-locked loop function is disabled.

INTV$_{CC}$ and DRV$_{CC}$ Connection

An internal low dropout regulator produces an internal 5V supply that powers the control circuitry and DRV$_{CC}$ for driving the internal power MOSFETs. Therefore, if the system does not have a 5V power rail, the LTM4601HV can be directly powered by V$_{IN}$. The gate driver current through the LDO is about 20mA. The internal LDO power dissipation can be calculated as:

$$P_{LDO\_LOSS} = 20mA \bullet (V_{IN} - 5V)$$

The LTM4601HV also provides the external gate driver voltage pin DRV$_{CC}$. If there is a 5V rail in the system, it is recommended to connect DRV$_{CC}$ pin to the external 5V rail. This is especially true for higher input voltages. Do not apply more than 6V to the DRV$_{CC}$ pin. A 5V output can be used to power the DRV$_{CC}$ pin with an external circuit as shown in Figure 18.

Parallel Operation of the Module

The LTM4601HV device is an inherently current mode controlled device. Parallel modules will have very good current sharing. This will balance the thermals on the design. The voltage feedback equation changes with the variable N as modules are paralleled:

$$V_{OUT} = 0.6V \bullet \frac{\frac{60.4k}{N} + R_{SET}}{R_{SET}}$$

or equivalently:

$$R_{SET} = \frac{\frac{60.4k}{N}}{\left(\frac{V_{OUT}}{0.6V} - 1\right)}$$

where N is the number of paralleled modules.

Figure 21 shows two LTM4601HV modules used in a parallel design. An LTM4601HV device can be used without the remote sense amplifier.

APPLICATIONS INFORMATION

Thermal Considerations and Output Current Derating

The power loss curves in Figures 7 and 8 can be used in coordination with the load current derating curves in Figures 9 to 16 for calculating an approximate θ_{JA} for the module with various heat sinking methods. Thermal models are derived from several temperature measurements at the bench and thermal modeling analysis. Thermal Application Note 103 provides a detailed explanation of the analysis for the thermal models and the derating curves. Tables 3 and 4 provide a summary of the equivalent θ_{JA} for the noted conditions. These equivalent θ_{JA} parameters are correlated to the measured values, and are improved with air flow. The case temperature is maintained at 100°C

or below for the derating curves. The maximum case temperature of 100°C is to allow for a rise of about 13°C to 25°C inside the µModule with a thermal resistance θ_{JC} from junction to case between 6°C/W to 9°C/W. This will maintain the maximum junction temperature inside the µModule below 125°C.

Safety Considerations

The LTM4601HV modules do not provide isolation from V_{IN} to V_{OUT}. There is no internal fuse. If required, a slow blow fuse with a rating twice the maximum input current needs to be provided to protect each unit from catastrophic failure.
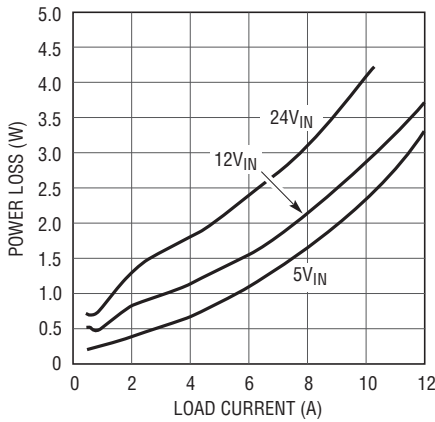
4601HV F07

Figure 7. 1.5V$_{OUT}$ Power Loss
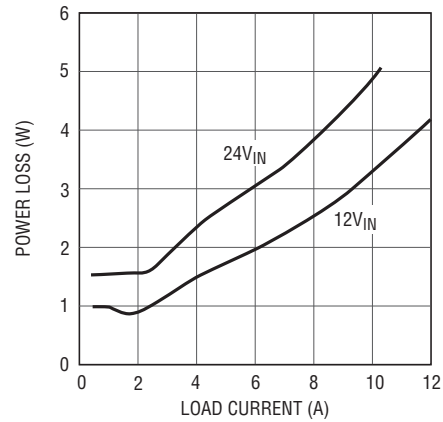
4601HV F08

Figure 8. 3.3V$_{OUT}$ Power Loss
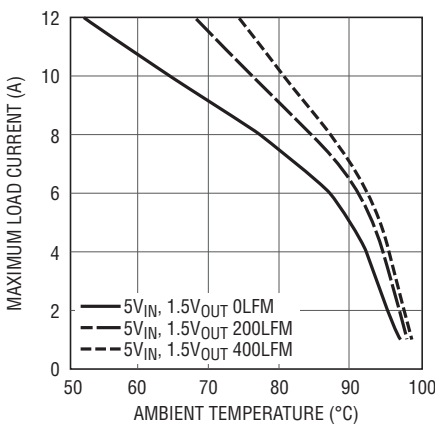
4601HV F09

Figure 9. No Heat Sink 5V$_{IN}$
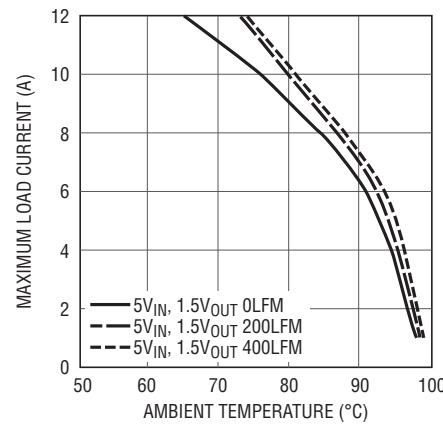
4601HV F10

Figure 10. BGA Heat Sink 5V$_{IN}$

APPLICATIONS INFORMATION
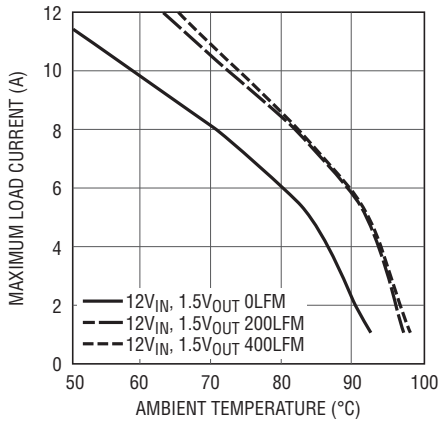
Figure 11. No Heat Sink 12V$_{IN}$
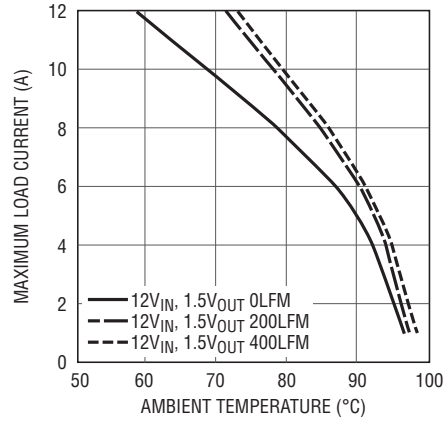
Figure 12. BGA Heat Sink 12V$_{IN}$
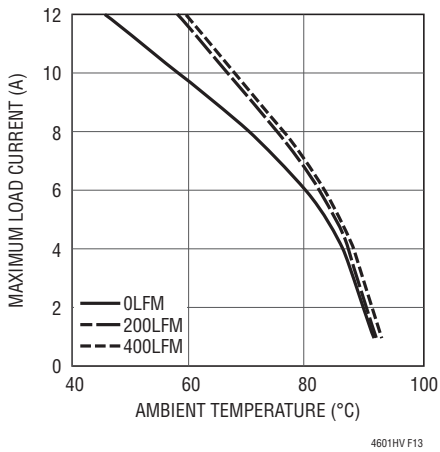
Figure 13. 12V$_{IN}$, 3.3V$_{OUT}$, No Heat Sink
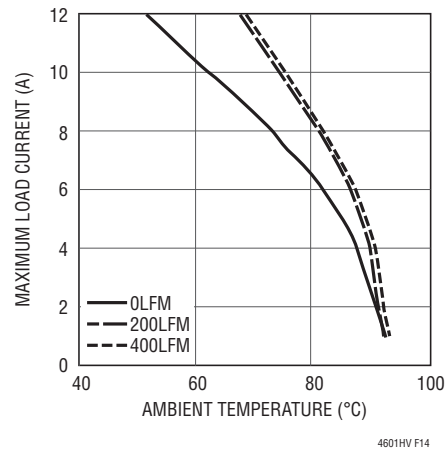
Figure 14. 12V$_{IN}$, 3.3V$_{OUT}$, BGA Heat Sink
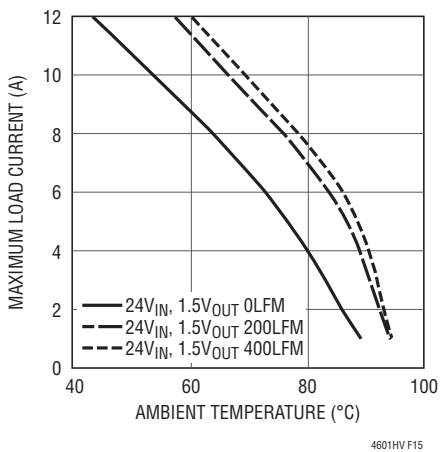
Figure 15. 24V$_{IN}$, 1.5V$_{OUT}$, No Heat Sink
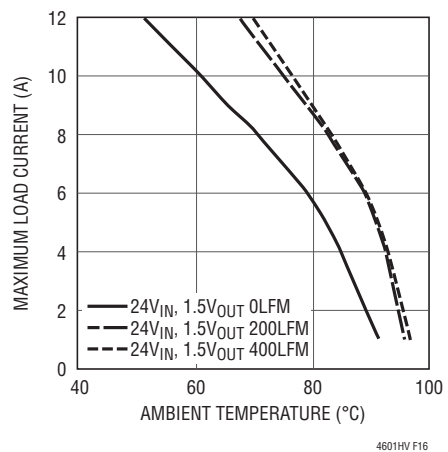
Figure 16. 24V$_{IN}$, 1.5V$_{OUT}$, BGA Heat Sink

APPLICATIONS INFORMATION

Table 2. Output Voltage Response Versus Component Matrix* (Refer to Figures 19 and 20), 0A to 6A Load Step

TYPICAL MEASURED VALUES

C$_{OUT1}$ VENDORS	PART NUMBER	C$_{OUT2}$ VENDORS	PART NUMBER
TDK	C4532X5R0J107MZ (100µF, 6.3V)	SANYO POSCAP	6TPE330MIL (330µF, 6.3V)
TAIYO YUDEN	JMK432BJ107MU-T (100µF, 6.3V)	SANYO POSCAP	2R5TPE470M9 (470µF, 2.5V)
TAIYO YUDEN	JMK316BJ226ML-T501 (22µF, 6.3V)	SANYO POSCAP	4TPE470MCL (470µF, 4V)

| V$_{OUT}$ (V)	C$_{IN}$ (CERAMIC)	C$_{IN}$ (BULK)	C$_{OUT1}$ (CERAMIC)	C$_{OUT2}$ (BULK)	C$_{COMP}$	C3	V$_{IN}$ (V)	DROOP (mV)	PEAK TO PEAK (mV)	RECOVERY TIME (µs)	LOAD STEP (A/µs)	R$_{SET}$ (kΩ)
1.2	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	47pF	5	70	140	30	6	60.4
1.2	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 2.5V	NONE	100pF	5	35	70	20	6	60.4
1.2	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	22pF	5	70	140	20	6	60.4
1.2	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	100pF	5	40	93	30	6	60.4
1.2	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	100pF	12	70	140	30	6	60.4
1.2	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 2.5V	NONE	100pF	12	35	70	20	6	60.4
1.2	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	22pF	12	70	140	20	6	60.4
1.2	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	100pF	12	49	98	20	6	60.4
1.5	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	100pF	5	48	100	35	6	40.2
1.5	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 2.5V	NONE	33pF	5	54	109	30	6	40.2
1.5	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	100pF	5	44	84	30	6	40.2
1.5	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	100pF	5	61	118	30	6	40.2
1.5	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	100pF	12	48	100	35	6	40.2
1.5	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 2.5V	NONE	33pF	12	54	109	30	6	40.2
1.5	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	100pF	12	44	89	25	6	40.2
1.5	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	100pF	12	54	108	25	6	40.2
1.8	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	47pF	5	48	100	30	6	30.1
1.8	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 2.5V	NONE	100pF	5	44	90	20	6	30.1
1.8	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	100pF	5	68	140	30	6	30.1
1.8	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	100pF	5	65	130	30	6	30.1
1.8	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	100pF	12	60	120	30	6	30.1
1.8	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 2.5V	NONE	100pF	12	60	120	30	6	30.1
1.8	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	100pF	12	68	140	30	6	30.1
1.8	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	100pF	12	65	130	20	6	30.1
2.5	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 4V	NONE	100pF	5	48	103	30	6	19.1
2.5	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	220pF	5	56	113	30	6	19.1
2.5	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	NONE	5	57	116	30	6	19.1
2.5	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	100pF	5	60	115	25	6	19.1
2.5	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 4V	NONE	100pF	12	48	103	30	6	19.1
2.5	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	NONE	12	51	102	30	6	19.1
2.5	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	220pF	12	56	113	30	6	19.1
2.5	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	220pF	12	70	140	25	6	19.1
3.3	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	100pF	7	120	240	30	6	13.3
3.3	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 4V	NONE	100pF	7	110	214	30	6	13.3
3.3	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	100pF	7	110	214	30	6	13.3
3.3	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	100pF	7	114	230	30	6	13.3
3.3	2 × 10µF 35V	150µF 35V	1 × 100µF 6.3V	470µF 4V	NONE	100pF	12	110	214	30	6	13.3
3.3	2 × 10µF 35V	150µF 35V	3 × 22µF 6.3V	470µF 4V	NONE	150pF	12	110	214	35	6	13.3
3.3	2 × 10µF 35V	150µF 35V	2 × 100µF 6.3V	330µF 6.3V	NONE	100pF	12	110	214	35	6	13.3
3.3	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	100pF	12	114	230	30	6	13.3
5	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	22pF	15	188	375	25	6	8.25
5	2 × 10µF 35V	150µF 35V	4 × 100µF 6.3V	NONE	NONE	22pF	20	159	320	25	6	8.25

* X7R is recommended for extended temperature range.

APPLICATIONS INFORMATION

Table 3. 1.5V Output at 12A

DERATING CURVE	V$_{IN}$ (V)	POWER LOSS CURVE	AIR FLOW (LFM)	HEAT SINK	θ$_{JA}$ (°C/W) LGA	θ$_{JA}$ (°C/W) BGA
Figures 9, 11, 15	5, 12, 24	Figure 7	0	None	15.2	15.7
Figures 9, 11, 15	5, 12, 24	Figure 7	200	None	14	14.5
Figures 9, 11, 15	5, 12, 24	Figure 7	400	None	12	12.5
Figures 10, 12, 16	5, 12, 24	Figure 7	0	BGA Heat Sink	13.9	14.4
Figures 10, 12, 16	5, 12, 24	Figure 7	200	BGA Heat Sink	11.3	11.8
Figures 10, 12, 16	5, 12, 24	Figure 7	400	BGA Heat Sink	10.25	10.75

Table 4. 3.3V Output at 12A

DERATING CURVE	V$_{IN}$ (V)	POWER LOSS CURVE	AIR FLOW (LFM)	HEAT SINK	θ$_{JA}$ (°C/W) LGA	θ$_{JA}$ (°C/W) BGA
Figure 13	12	Figure 8	0	None	15.2	15.7
Figure 13	12	Figure 8	200	None	14.6	15.0
Figure 13	12	Figure 8	400	None	13.4	13.9
Figure 14	12	Figure 8	0	BGA Heat Sink	13.9	14.4
Figure 14	12	Figure 8	200	BGA Heat Sink	11.1	11.6
Figure 14	12	Figure 8	400	BGA Heat Sink	10.5	11.0

Heat Sink Manufacturer

Aavid Thermalloy	Part No: 375424B00034G	Phone: 603-224-9988

APPLICATIONS INFORMATION

Layout Checklist/Example

The high integration of LTM4601HV makes the PCB board layout very simple and easy. However, to optimize its electrical and thermal performance, some layout considerations are still necessary.

- Use large PCB copper areas for high current path, including V_{IN}, PGND and V_{OUT}. It helps to minimize the PCB conduction loss and thermal stress.

- Place high frequency ceramic input and output capacitors next to the V_{IN}, PGND and V_{OUT} pins to minimize high frequency noise.

- Place a dedicated power ground layer underneath the unit. Refer frequency synchronization source to power ground.

- To minimize the via conduction loss and reduce module thermal stress, use multiple vias for interconnection between top layer and other power layers.

- Do not put vias directly on pads unless they are capped.

- Use a separated SGND copper area for components connected to signal pins. Connect the SGND to PGND underneath the unit.

Figure 17 gives a good example of the recommended layout.
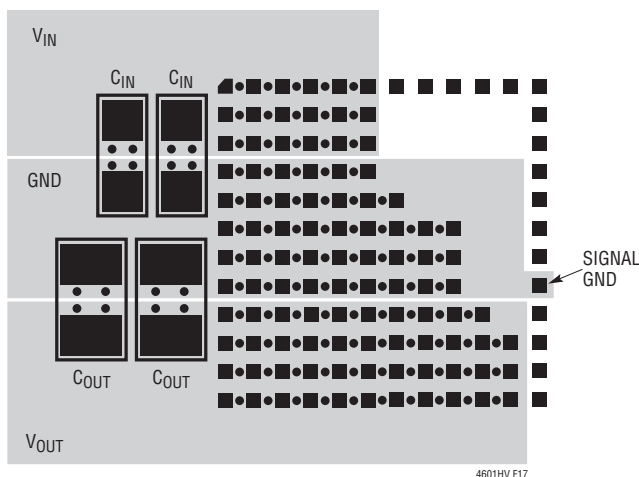
Figure 17. Recommended Layout (LGA and BGA PCB Layouts Are Identical with the Exception of Circle Pads for BGA. See Package Description.)

Frequency Adjustment

The LTM4601HV is designed to typically operate at 850kHz across most input conditions. The f_{SET} pin is normally left open. The switching frequency has been optimized for maintaining constant output ripple noise over most operating ranges. The 850kHz switching frequency and the 400ns minimum off time can limit operation at higher duty cycles like 5V to 3.3V, and produce excessive inductor ripple currents for lower duty cycle applications like 28V to 5V. The $5V_{OUT}$ and $3.3V_{OUT}$ drop out curves are modified by adding an external resistor on the f_{SET} pin to allow for lower input voltage operation, or higher input voltage operation.

Example for 5V Output

LTM4601HV minimum on-time = 100ns
$t_{ON} = ((V_{OUT} \cdot 10pF)/I_{fSET})$, for $V_{OUT} > 4.8V$ use 4.8V

LTM4601HV minimum off-time = 400ns

$t_{OFF} = t - t_{ON}$, where t = 1/Frequency

Duty Cycle = t_{ON}/t or V_{OUT}/V_{IN}

Equations for setting frequency:

$I_{fSET} = (V_{IN}/(3 \cdot R_{fSET}))$, for 28V operation, $I_{fSET} = 238\mu A$, $t_{ON} = ((4.8 \cdot 10pF)/I_{fSET})$, $t_{ON} = 202ns$, where the internal R_{fSET} is 39.2k. Frequency = $(V_{OUT}/(V_{IN} \cdot t_{ON})) = (5V/(28 \cdot 202ns)) \sim 884kHz$. The inductor ripple current begins to get high at the higher input voltages due to a larger voltage across the inductor. This is noted in the Typical Inductor Ripple Current vs Duty Cycle graph (Figure 3) where $I_L \approx 10A$ at 20% duty cycle. The inductor ripple current can be lowered at the higher input voltages by adding an external resistor from f_{SET} to ground to increase the switching frequency. A 7A ripple current is chosen, and the total peak current is equal to 1/2 of the 7A ripple current plus the output current. The 5V output current is limited to 8A, so the total peak current is less than 11.5A. This is below the 14A peak specified value. A 100k resistor is placed from f_{SET} to ground, and the parallel combination of 100k and 39.2k equates to 28k. The I_{fSET} calculation with 28k and 28V input voltage equals 333μA. This equates to a t_{ON} of 144ns. This will increase the switching frequency from ~884kHz to ~1.24MHz for the 28V to 5V conversion.

APPLICATIONS INFORMATION

The minimum on-time is above 100ns at 28V input. Since the switching frequency is approximately constant over input and output conditions, then the lower input voltage range is limited to 10V for the 1.24MHz operation due to the 400ns minimum off-time. Equation: $t_{ON} = (V_{OUT}/V_{IN})$ • (1/Frequency) equates to a 400ns on-time, and a 400ns off-time. The "V_{IN} to V_{OUT} Step-Down Ratio Curve" reflects an operating range of 10V to 28V for 1.24MHz operation with a 100k resistor to ground as shown in Figure 18, and an 8V to 16V operation for f_{SET} floating. These modifications are made to provide wider input voltage ranges for the 5V output designs while limiting the inductor ripple current, and maintaining the 400ns minimum off-time.

Example for 3.3V Output

LTM4601HV minimum on-time = 100ns
$t_{ON} = ((V_{OUT} • 10pF)/I_{fSET})$

LTM4601HV minimum off-time = 400ns
$t_{OFF} = t - t_{ON}$, where t = 1/Frequency

Duty Cycle (DC) = t_{ON}/t or V_{OUT}/V_{IN}

Equations for setting frequency:

$I_{fSET} = (V_{IN}/(3 • R_{fSET}))$, for 28V operation, I_{fSET} = 238µA, $t_{ON} = ((3.3 • 10pF)/I_{fSET})$, t_{ON} = 138.7ns, where the internal R_{fSET} is 39.2k. Frequency = $(V_{OUT}/(V_{IN} • t_{ON}))$ = (3.3V/(28 • 138.7ns)) ~ 850kHz. The minimum on-time and minimum off-time are within specification at 139ns and 1037ns. The 4.5V minimum input for converting 3.3V output will not meet the minimum off-time specification of 400ns. t_{ON} = 868ns, Frequency = 850kHz, t_{OFF} = 315ns.

Solution

Lower the switching frequency at lower input voltages to allow for higher duty cycles, and meet the 400ns minimum off-time at 4.5V input voltage. The off-time should be about 500ns, which includes a 100ns guard band. The duty cycle for (3.3V/4.5V) = ~73%. Frequency = $(1 - DC)/t_{OFF}$ or (1 − 0.73)/500ns = 540kHz. The switching frequency needs to be lowered to 540kHz at 4.5V input. t_{ON} = DC/frequency, or 1.35µs. The f_{SET} pin voltage compliance is 1/3 of V_{IN}, and the I_{fSET} current equates to 38µA with the internal 39.2k. The I_{fSET} current needs to be 24µA for 540kHz operation. As shown in Figure 19, a resistor can be placed from V_{OUT} to f_{SET} to lower the effective I_{fSET} current out of the f_{SET} pin to 24µA. The f_{SET} pin is 4.5V/3 =1.5V and V_{OUT} = 3.3V, therefore 130k will source 14µA into the f_{SET} node and lower the I_{fSET} current to 24µA. This enables the 540kHz operation and the 4.5V to 28V input operation for down converting to 3.3V output. The frequency will scale from 540kHz to 1.1 MHz over this input range. This provides for an effective output current of 8A over the input range.

Figure 18. 5V at 8A Design Without Differential Amplifier

APPLICATIONS INFORMATION

Figure 19. 3.3V at 10A Design

Figure 20. Typical 22V to 28V, 1.5V at 10A Design, 500kHz

4601hvfb

APPLICATIONS INFORMATION

Figure 21. 2-Phase Parallel, 3.3V at 20A Design

TYPICAL APPLICATIONS

Figure 22. Dual Outputs (3.3V and 2.5V) with Coincident Tracking

Figure 23. Dual Outputs (1.8V and 1.5V) with Coincident Tracking

4601hvfb

PACKAGE DESCRIPTION

Please refer to http://www.linear.com/designtools/packaging/ for the most recent package drawings.

BGA Package
118-Lead (15mm × 15mm × 3.42mm)
(Reference LTC DWG # 05-08-1903 Rev A)
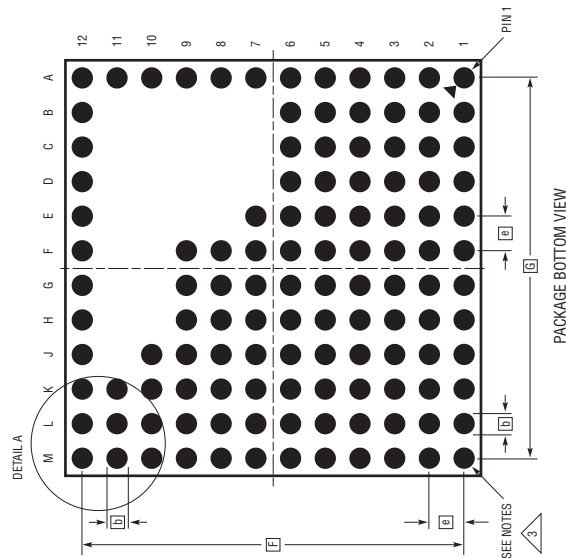
PACKAGE BOTTOM VIEW

PIN 1

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
2. ALL DIMENSIONS ARE IN MILLIMETERS
3. BALL DESIGNATION PER JESD MS-028 AND JEP95
4. DETAILS OF PIN #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE PIN #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE
5. PRIMARY DATUM -Z- IS SEATING PLANE
6. SOLDER BALL COMPOSITION IS 96.5% Sn/3.0% Ag/0.5% Cu

PACKAGE IN TRAY LOADING ORIENTATION

LTMXXXXX
μModule

COMPONENT PIN "A1"

TRAY PIN 1 BEVEL

BGA 118 0112 REV A

DETAIL B
PACKAGE SIDE VIEW

SUBSTRATE

MOLD CAP

0.27 – 0.37

2.45 – 2.55

DETAIL B

Øb (118 PLACES)

DETAIL A
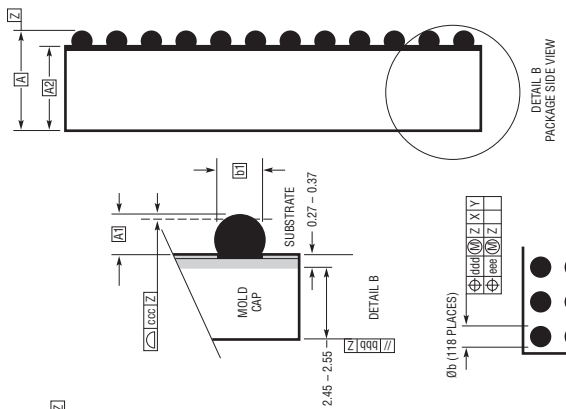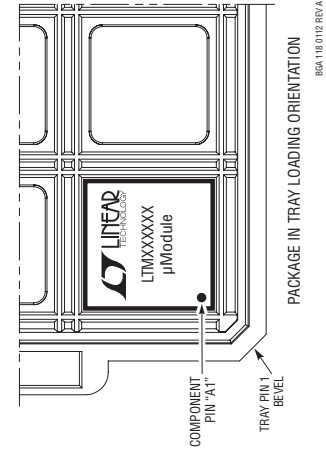
DIMENSIONS				
SYMBOL	MIN	NOM	MAX	NOTES
A	3.22	3.42	3.62	
A1	0.50	0.60	0.70	
A2	2.72	2.82	2.92	
b	0.60	0.75	0.90	
b1	0.60	0.63	0.66	
D		15.0		
E		15.0		
e		1.27		
F		13.97		
G		13.97		
aaa			0.15	
bbb			0.10	
ccc			0.20	
ddd			0.30	
eee			0.15	

TOTAL NUMBER OF BALLS: 118

PACKAGE TOP VIEW

PIN "A1" CORNER

SUGGESTED PCB LAYOUT TOP VIEW

6.9850
5.7150
4.4450
3.1750
1.9050
0.6350
0.0000
0.6350
1.9050
3.1750
4.4450
5.7150
6.9850

0.630 ±0.025 Ø 118x

4601hvfb

25

PACKAGE DESCRIPTION

Please refer to http://www.linear.com/designtools/packaging/ for the most recent package drawings.

PACKAGE BOTTOM VIEW

DETAIL A

SEE NOTES 3

C(0.30) PAD 1

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
2. ALL DIMENSIONS ARE IN MILLIMETERS
3. BALL DESIGNATION PER JESD MS-028 AND JEP95
4. DETAILS OF PIN #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE PIN #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE
5. PRIMARY DATUM -Z- IS SEATING PLANE

PACKAGE IN TRAY LOADING ORIENTATION

LGA 118 1011 REV A

LTMXXXXX
µModule

COMPONENT PIN "A1"

TRAY PIN 1 BEVEL

LGA Package
118-Lead (15mm × 15mm × 2.82mm)
(Reference LTC DWG # 05-08-1801 Rev A)

DETAIL B PACKAGE SIDE VIEW

SUBSTRATE

MOLD CAP

DETAIL B

DETAIL A

0.630 ±0.025 SQ. 118x

DIMENSIONS				
SYMBOL	MIN	NOM	MAX	NOTES
A	2.72	2.82	2.92	
b	0.60	0.63	0.66	
D		15.00		
E		15.00		
e		1.27		
F		13.97		
G		13.97		
H1	0.27	0.32	0.37	
H2	2.45	2.50	2.55	
aaa			0.15	
bbb			0.10	
eee			0.05	

TOTAL NUMBER OF LGA PADS: 118

PACKAGE TOP VIEW

PIN "A1" CORNER

SUGGESTED PCB LAYOUT TOP VIEW

0.630 ±0.025 Ø 118x

4601hvfb

LINEAR
TECHNOLOGY

PACKAGE DESCRIPTION

Table 5. Pin Assignment (Arranged by Pin Number)

PIN ID	FUNCTION	PIN ID	FUNCTION	PIN ID	FUNCTION	PIN ID	FUNCTION	PIN ID	FUNCTION	PIN ID	FUNCTION
A1	V_{IN}	B1	V_{IN}	C1	V_{IN}	D1	PGND	E1	PGND	F1	PGND
A2	V_{IN}	B2	V_{IN}	C2	V_{IN}	D2	PGND	E2	PGND	F2	PGND
A3	V_{IN}	B3	V_{IN}	C3	V_{IN}	D3	PGND	E3	PGND	F3	PGND
A4	V_{IN}	B4	V_{IN}	C4	V_{IN}	D4	PGND	E4	PGND	F4	PGND
A5	V_{IN}	B5	V_{IN}	C5	V_{IN}	D5	PGND	E5	PGND	F5	PGND
A6	V_{IN}	B6	V_{IN}	C6	V_{IN}	D6	PGND	E6	PGND	F6	PGND
A7	$INTV_{CC}$	B7	–	C7	–	D7	–	E7	PGND	F7	PGND
A8	PLLIN	B8	–	C8	–	D8	–	E8	–	F8	PGND
A9	TRACK/SS	B9	–	C9	–	D9	–	E9	–	F9	PGND
A10	RUN	B10	–	C10	–	D10	–	E10	–	F10	–
A11	COMP	B11	–	C11	–	D11	–	E11	–	F11	–
A12	MPGM	B12	f_{SET}	C12	MARG0	D12	MARG1	E12	DRV_{CC}	F12	V_{FB}

PIN ID	FUNCTION	PIN ID	FUNCTION	PIN ID	FUNCTION	PIN ID	FUNCTION	PIN ID	FUNCTION	PIN ID	FUNCTION
G1	PGND	H1	PGND	J1	V_{OUT}	K1	V_{OUT}	L1	V_{OUT}	M1	V_{OUT}
G2	PGND	H2	PGND	J2	V_{OUT}	K2	V_{OUT}	L2	V_{OUT}	M2	V_{OUT}
G3	PGND	H3	PGND	J3	V_{OUT}	K3	V_{OUT}	L3	V_{OUT}	M3	V_{OUT}
G4	PGND	H4	PGND	J4	V_{OUT}	K4	V_{OUT}	L4	V_{OUT}	M4	V_{OUT}
G5	PGND	H5	PGND	J5	V_{OUT}	K5	V_{OUT}	L5	V_{OUT}	M5	V_{OUT}
G6	PGND	H6	PGND	J6	V_{OUT}	K6	V_{OUT}	L6	V_{OUT}	M6	V_{OUT}
G7	PGND	H7	PGND	J7	V_{OUT}	K7	V_{OUT}	L7	V_{OUT}	M7	V_{OUT}
G8	PGND	H8	PGND	J8	V_{OUT}	K8	V_{OUT}	L8	V_{OUT}	M8	V_{OUT}
G9	PGND	H9	PGND	J9	V_{OUT}	K9	V_{OUT}	L9	V_{OUT}	M9	V_{OUT}
G10	–	H10	–	J10	V_{OUT}	K10	V_{OUT}	L10	V_{OUT}	M10	V_{OUT}
G11	–	H11	–	J11	–	K11	V_{OUT}	L11	V_{OUT}	M11	V_{OUT}
G12	PGOOD	H12	SGND	J12	$V_{OSNS}+$	K12	$DIFFV_{OUT}$	L12	V_{OUT_LCL}	M12	$V_{OSNS}-$

PACKAGE DESCRIPTION

Table 6. Pin Assignment (Arranged by Pin Function)

PIN	NAME
A1	V_{IN}
A2	V_{IN}
A3	V_{IN}
A4	V_{IN}
A5	V_{IN}
A6	V_{IN}
B1	V_{IN}
B2	V_{IN}
B3	V_{IN}
B4	V_{IN}
B5	V_{IN}
B6	V_{IN}
C1	V_{IN}
C2	V_{IN}
C3	V_{IN}
C4	V_{IN}
C5	V_{IN}
C6	V_{IN}

PIN	NAME
D1	PGND
D2	PGND
D3	PGND
D4	PGND
D5	PGND
D6	PGND
E1	PGND
E2	PGND
E3	PGND
E4	PGND
E5	PGND
E6	PGND
E7	PGND
F1	PGND
F2	PGND
F3	PGND
F4	PGND
F5	PGND
F6	PGND
F7	PGND
F8	PGND
F9	PGND
G1	PGND
G2	PGND
G3	PGND
G4	PGND
G5	PGND
G6	PGND
G7	PGND
G8	PGND
G9	PGND
H1	PGND
H2	PGND
H3	PGND
H4	PGND
H5	PGND
H6	PGND
H7	PGND
H8	PGND
H9	PGND

PIN	NAME
J1	V_{OUT}
J2	V_{OUT}
J3	V_{OUT}
J4	V_{OUT}
J5	V_{OUT}
J6	V_{OUT}
J7	V_{OUT}
J8	V_{OUT}
J9	V_{OUT}
J10	V_{OUT}
K1	V_{OUT}
K2	V_{OUT}
K3	V_{OUT}
K4	V_{OUT}
K5	V_{OUT}
K6	V_{OUT}
K7	V_{OUT}
K8	V_{OUT}
K9	V_{OUT}
K10	V_{OUT}
K11	V_{OUT}
L1	V_{OUT}
L2	V_{OUT}
L3	V_{OUT}
L4	V_{OUT}
L5	V_{OUT}
L6	V_{OUT}
L7	V_{OUT}
L8	V_{OUT}
L9	V_{OUT}
L10	V_{OUT}
L11	V_{OUT}
M1	V_{OUT}
M2	V_{OUT}
M3	V_{OUT}
M4	V_{OUT}
M5	V_{OUT}
M6	V_{OUT}
M7	V_{OUT}
M8	V_{OUT}
M9	V_{OUT}
M10	V_{OUT}
M11	V_{OUT}

PIN	NAME
A7	$INTV_{CC}$
A8	PLLIN
A9	TRACK/SS
A10	RUN
A11	COMP
A12	MPGM
B12	f_{SET}
C12	MARG0
D12	MARG1
E12	DRV_{CC}
F12	V_{FB}
G12	PGOOD
H12	SGND
J12	V_{OSNS}^+
K12	$DIFFV_{OUT}$
L12	V_{OUT_LCL}
M12	V_{OSNS}^-

PIN	NAME
B7	-
B8	-
B9	-
B10	-
B11	-
C7	-
C8	-
C9	-
C10	-
C11	-
D7	-
D8	-
D9	-
D10	-
D11	-
E8	-
E9	-
E10	-
E11	-
F10	-
F11	-
G10	-
G11	-
H10	-
H11	-
J11	-

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REVISION HISTORY (Revision history begins at Rev B)

REV	DATE	DESCRIPTION	PAGE NUMBER
B	03/12	Revised entire data sheet to include the BGA package.	1–30

PACKAGE PHOTOS
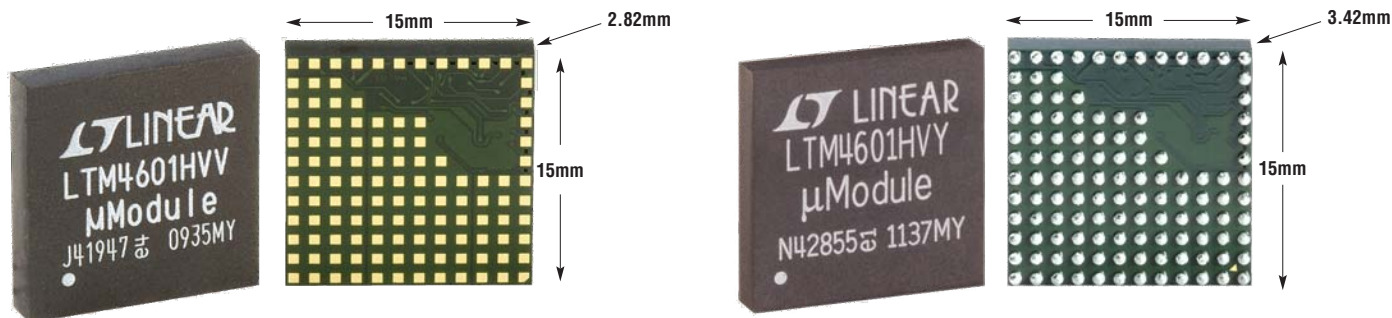
RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTM4628	26V, Dual 8A, DC/DC Step-Down µModule Regulator	$4.5V \leq V_{IN} \leq 26.5V$, $0.6V \leq V_{OUT} \leq 5V$, Remote Sense Amplifier, Internal Temperature Sensing Output, 15mm × 15mm × 4.32mm LGA
LTM4627	20V, 15A DC/DC Step-Down µModule Regulator	$4.5V \leq V_{IN} \leq 20V$, $0.6V \leq V_{OUT} \leq 5V$, PLL Input, V_{OUT} Tracking, Remote Sense Amplifier, 15mm × 15mm × 4.32mm LGA
LTM4611	$1.5V_{IN(MIN)}$, 15A DC/DC Step-Down µModule Regulator	$1.5V \leq V_{IN} \leq 5.5V$, $0.8V \leq V_{OUT} \leq 5V$, PLL Input, Remote Sense Amplifier, V_{OUT} Tracking, 15mm × 15mm × 4.32mm LGA
LTM4613	8A EN55022 Class B DC/DC Step-Down µModule Regulator	$5V \leq V_{IN} \leq 36V$, $3.3V \leq V_{OUT} \leq 15V$, PLL Input, V_{OUT} Tracking and Margining, 15mm × 15mm × 4.32mm LGA
LTM4601AHV	28V, 12A DC/DC Step-Down µModule Regulator	$4.5V \leq V_{IN} \leq 28V$, $0.6V \leq V_{OUT} \leq 5V$, PLL Input, Remote Sense Amplifier, V_{OUT} Tracking and Margining, 15mm × 15mm × 2.82mm LGA or 15mm × 15mm × 3.42mm BGA
LTM4601A	20V, 12A DC/DC Step-Down µModule Regulator	$4.5V \leq V_{IN} \leq 20V$, $0.6V \leq V_{OUT} \leq 5V$, PLL Input, Remote Sense Amplifier, V_{OUT} Tracking and Margining, 15mm × 15mm × 2.82mm LGA or 15mm × 15mm × 3.42mm BGA
LTM8027	60V, 4A DC/DC Step-Down µModule Regulator	$4.5V \leq V_{IN} \leq 60V$, $2.5V \leq V_{OUT} \leq 24V$, CLK Input, 15mm × 15mm × 4.32mm LGA
LTM8032	36V, 2A EN55022 Class B DC/DC Step-Down µModule Regulator	$3.6V \leq V_{IN} \leq 36V$, $0.8V \leq V_{OUT} \leq 10V$, Synchronizable, 9mm × 15mm × 2.82mm LGA or 9mm × 15mm × 3.42mm BGA
LTM8061	32V, 2A Step-Down µModule Battery Charger with Programmable Input Current Limit	Compatible with Single Cell or Dual Cell Li-Ion or Li-Poly Battery Stacks (4.1V, 4.2V, 8.2V, or 8.4V), $4.95V \leq V_{IN} \leq 32V$, C/10 or Adjustable Timer Charge Termination, NTC Resistor Monitor Input, 9mm × 15mm × 4.32mm LGA

4601hvfb

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